

Supporting Information

Hydrogel- and Organohydrogel-based Stretchable, Ultrasensitive, Transparent, Room-temperature and Real-time NO₂ Sensors and the Mechanism

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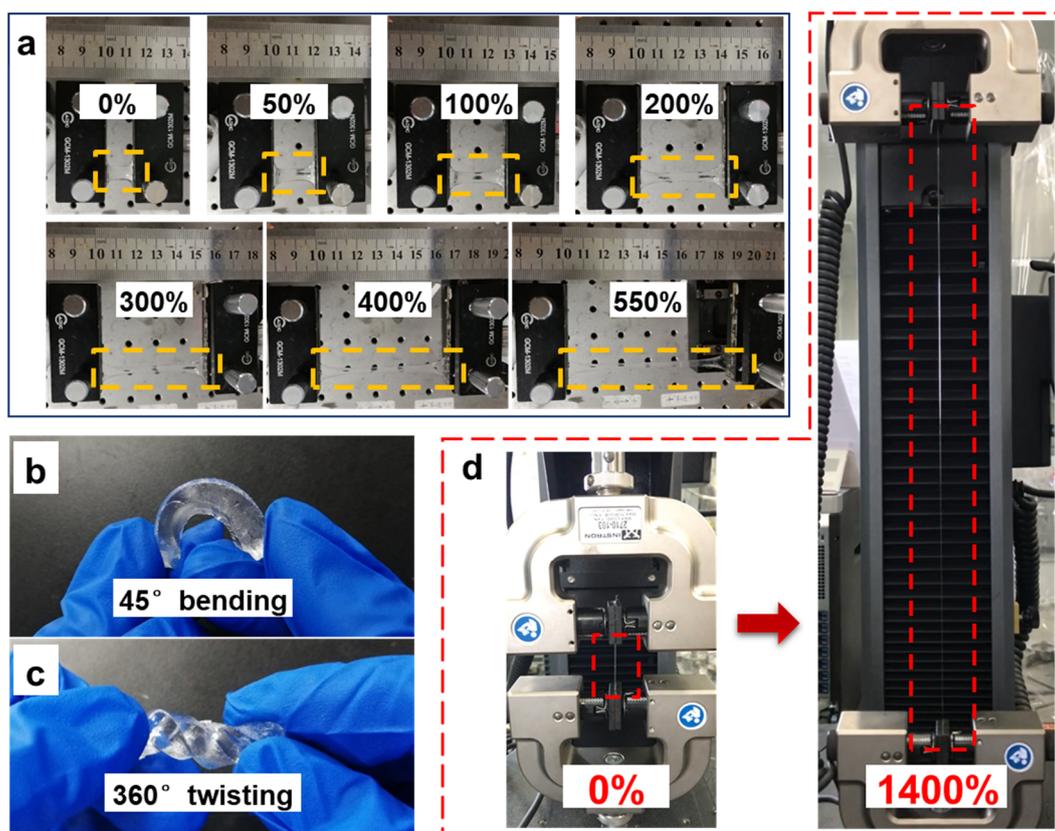


Fig. S1 The photographs showing the DN hydrogel withstands (a) a series of tensile strains from 0% to 550%, (b) 45° bending strain, (c) 360° twisting strain and (d) 1400% tensile strain.

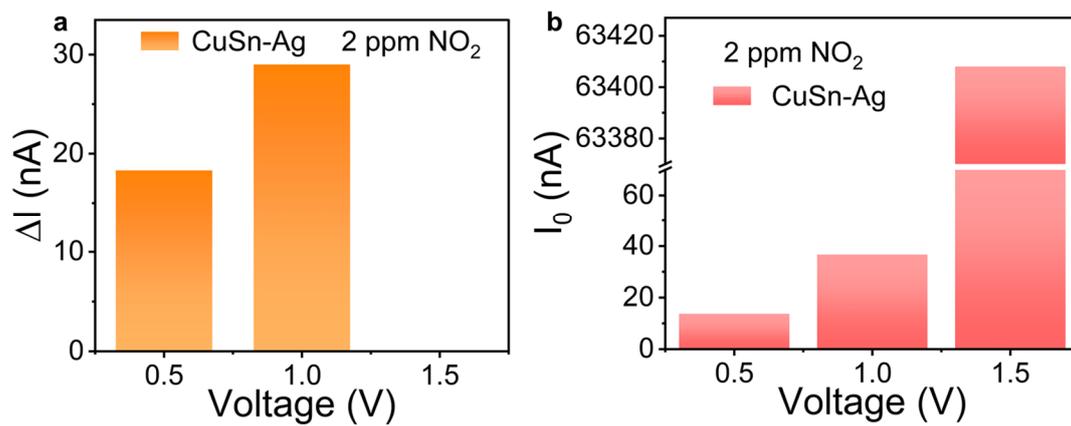


Fig. S2 The current change ΔI (a) and base current I_0 (b) of the CuSn-Ag sensor in response to 2 ppm NO₂ at the bias voltages of 0.5, 1.0 and 1.5 V.

Calculation of the limit of detection (LOD).

The calculation of LOD was executed by equations S1 and S2. The procedure was as follow:

1. Execute the 5th order polynomial fit for the baseline of response versus time curve before exposure to NO₂ (Fig. S3).
2. Extract N = 11 data points (Y_i) from the baseline.
3. Calculate the noise according to equation S1.
4. Extract the sensitivity (slope) from the response versus the time curve (Figure 4c).
5. Calculate the LOD according to equation S2.

$$Noise = \sqrt{\frac{\sum(Y-Y_i)^2}{N-1}} \quad (\text{Equation S1})$$

$$LOD = \frac{3 \times Noise}{Slope} \quad (\text{Equation S2})$$

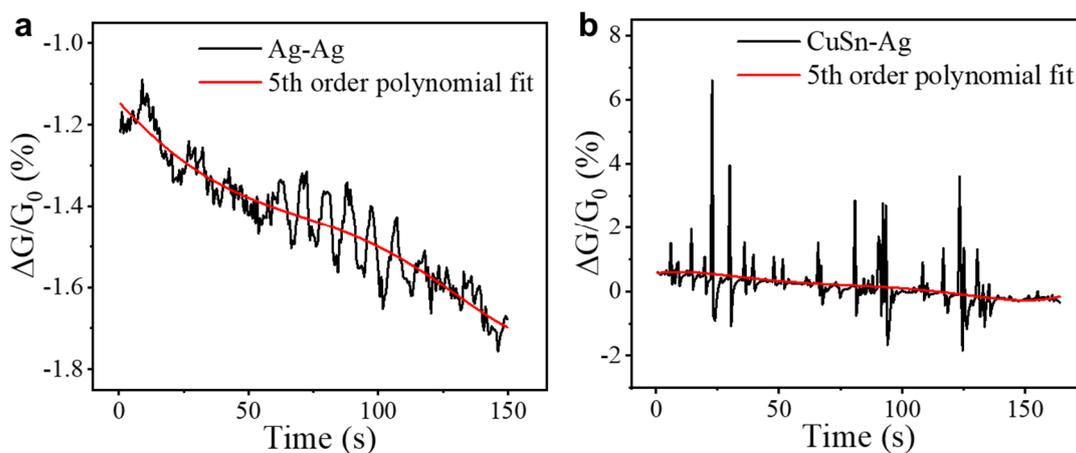


Fig. S3 (a) and (b) The 5th order polynomial fitted results for the background responses of Ag-Ag and CuSn-Ag sensors, respectively, before exposure to NO₂.

Table S1. 5th order polynomial fitting data for the Ag-Ag NO₂ sensor.

Time(s)	Y_i	Y	(Y_i-Y)²
0.59082	-1.21781	-1.14853	0.0048
10.7749	-1.12336	-1.21423	0.00826
20.35986	-1.26956	-1.26761	3.80E-06
30.54395	-1.29414	-1.31461	4.19E-04
40.729	-1.33393	-1.35222	3.34E-04
50.91309	-1.39506	-1.38211	1.68E-04
60.49805	-1.3789	-1.40537	7.01E-04
70.68213	-1.3197	-1.42758	0.01164
80.86621	-1.3679	-1.45	0.00674
90.45117	-1.41707	-1.47362	0.0032
100.63623	-1.62214	-1.50327	0.01413

Table S2. 5th order polynomial fitting data for the CuSn-Ag NO₂ sensor.

Time(s)	Y_i	Y	(Y_i-Y)²
0.58984	0.58415	0.56492	3.70E-04
10.77393	0.45332	0.5984	0.02105
20.95801	0.25835	0.55044	0.08532
30.54297	-1.07907	0.47352	2.41055
40.72705	0.17063	0.38716	0.04689
50.91211	0.2284	0.31236	0.00705
60.49707	0.23498	0.25763	5.13E-04
70.68115	0.14578	0.21377	0.00462
80.26611	0.14961	0.17914	8.72E-04
90.4502	1.68626	0.1398	2.39154
100.63379	-0.00948	0.08837	0.00957

Table S3. Calculated noises and LODs for the Ag-Ag and CuSn-Ag NO₂ sensors.

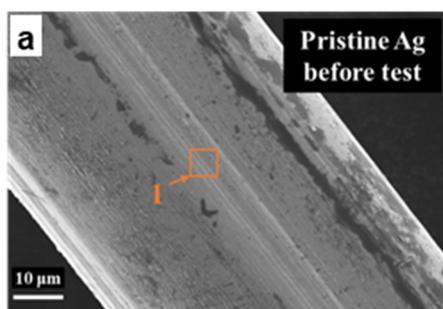
Sensor	Noise (%)	Sensitivity (%ppm⁻¹)	LOD (ppb)
Ag-Ag	0.0701	31.18	6.8
CuSn-Ag	0.7354	60.02	36.8

Table S4. Performance comparison of various NO₂ sensing materials in terms of sensitivity, response/recovery time, working temperature, LOD, deformability and transparency.

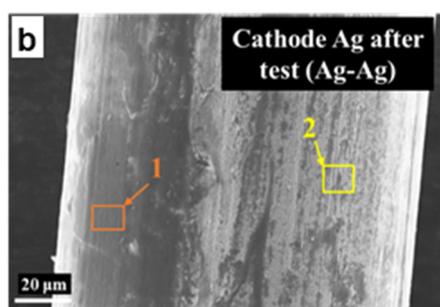
Sensing materials	Sensitivity	t _{resp} /t _{rec} (s)	Temp.	LOD (ppm)	Deformability	Transparency	Ref.
sulfonated rGO	44.3 %/ppm	/	RT	3.6	No	No	1
ethylenediamine-modified rGO	15.9 %/ppm	/	RT	0.07	No	No	
WO ₃ nanoplates	131.75@100 ppm (R _g /R _a)	/	100 °C	5	No	No	2
Au-WO ₃	28.626 /ppm (R _g /R _a)	4/59	100 °C	<0.25	No	No	3
rGO/ZnO	12@50 ppb (R _g /R _a)	5.1min/7.5min	100 °C	0.005	No	No	4
chemically functionalized RGO	2.3 %/ppm	284/363	RT	0.07	No	No	5
Au@Te	28 /ppm (R _a /R _g)	11.3 (t _{resp})	RT	0.000083	No	No	6
WSe ₂ nanosheets	1.55 /ppm (R _a /R _g)	/	RT	0.008	bending	No	7
Pt-ZnO/porous RGO	43.28 %@5 ppm	/	RT	0.1	90° bending	No	8
SnO ₂ /RGO	4.3 %/ppm	177/260	RT	0.0028	150° bending	No	9
PPy/N-MWCNT	24.82 %@5 ppm	65/668	RT	<0.25	bending	No	10
PbS CQD	41 %/ppm (R _a /R _g)	12/37	RT	0.084	180° bending	No	11
MoS ₂ /RGO	6 %@1 ppm	6min/12 min	RT	0.0044	20% strain	No	12
MoS ₂	160 %@5 ppm	/	RT	<5	40% strain	No	13
rGO/ZnO	3.349 %/ppm	140/630	RT	0.0435	100% strain	No	14
PAM/Ca-alginate hydrogel	60.02 %/ppm	79.7/71.3	RT	0.0068	1400% strain	Yes	This work

The t_{resp} , t_{rec} , Temp., LOD, Ref. and RT mean the response time, recovery time, temperature, limit of detection, reference and room temperature, respectively.

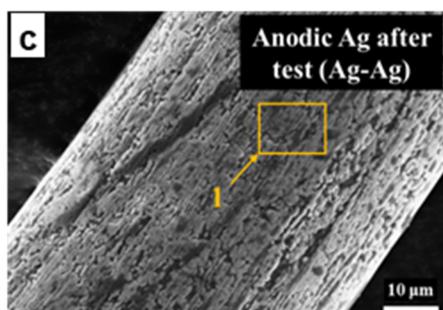
Fig. S4a shows the microscopic morphology of Ag electrode before undergoing long-time (6 h) sensing test toward 2 ppm NO₂. EDS analysis indicates that the element composition was Ag. For cathodic Ag that had undergone sensing test (Fig. S4b), its morphology was similar with the pristine Ag but O element appeared on its surface, which was ascribed to the residual hydrogel. As shown in Fig. S4c, the surface of anodic Ag that had undergone long-term sensing test showed abundant cracks, revealing that the anode was oxidized and corroded. During all the EDS analyses, the C elements resulted from the conductive adhesive tape that was utilized to immobilize samples on the supporting SEM stage.



Elements	C	O	Ag
1	-	-	100.00



Elements	C	O	Ag
1	54.92	17.00	28.08
2	30.43	-	69.57



Elements	C	Ag
1	33.23	66.77

Fig. S4 SEM images (left) and corresponding EDS results (right) of anodic and cathodic electrodes of Ag-Ag sensor before and after the continuous detection of 2 ppm NO₂ for

6 h. (a) The pristine Ag before sensing test. (b) The cathodic Ag after sensing test. (c)
The anodic Ag after sensing test.

Fig. S5a shows the microscopic morphology of CuSn electrode before undergoing the NO₂ sensing test. EDS analysis shows that the atomic ratio of Cu: Sn was about 2: 1. For cathodic Ag and anodic CuSn that had undergone long-term (6 h) sensing test (Fig. S5b-c), there were obvious residual hydrogel on the surfaces and O element was observed in anode and cathode. However, different from the anode of Ag-Ag sensor (Fig. S4c), no obvious crack was detected on the anodic CuSn, presenting its superior corrosion resistance of the CuSn-Ag sensor.

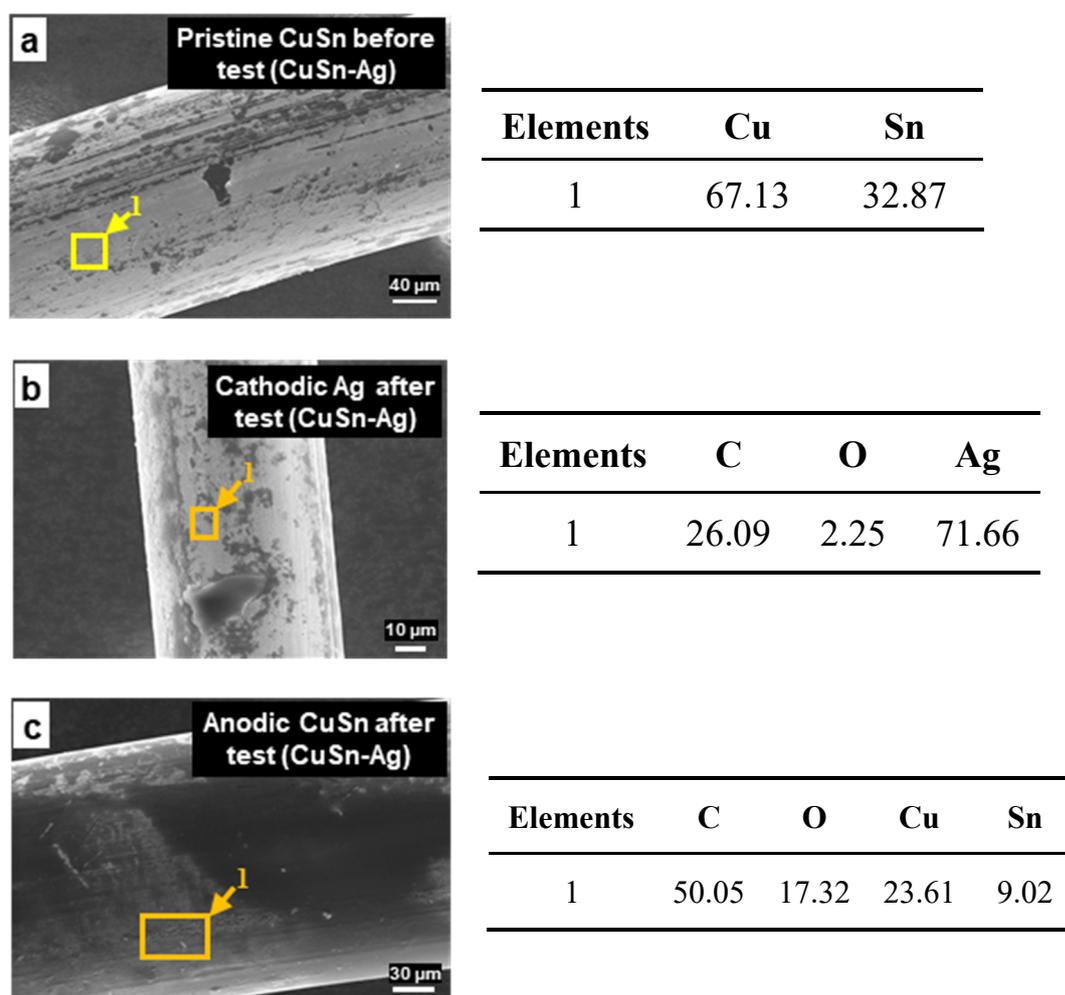


Fig. S5. SEM images (left) and corresponding EDS results (right) of anodic and cathodic electrodes of CuSn-Ag sensor before and after gas sensing tests toward 2 ppm NO₂ for 6 h. (a) The pristine CuSn before NO₂ sensing test. (b) The cathodic Ag after NO₂ sensing test. (c) The anodic CuSn after NO₂ sensing test.

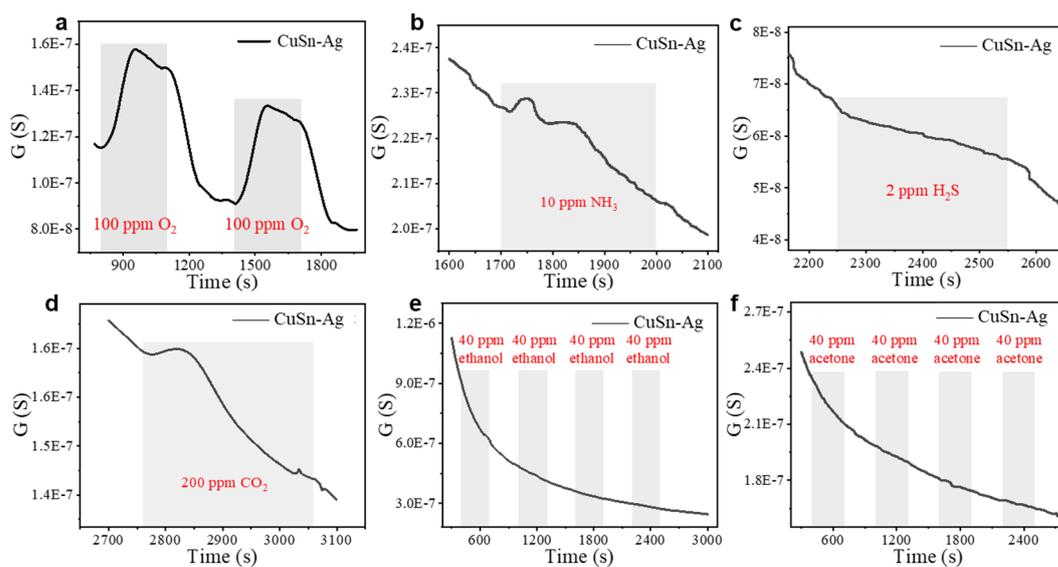


Fig. S6. Investigation of the selectivity of the CuSn-Ag hydrogel sensor toward NO_2 .

Time-dependent conductance change of the sensor in response to (a) 100 ppm O_2 , (b) 10 ppm NH_3 , (c) 2 ppm H_2S , (d) 200 ppm CO_2 , (e) 40 ppm ethanol (repeated 4 cycles) and (f) 40 ppm acetone (repeated 4 cycles).

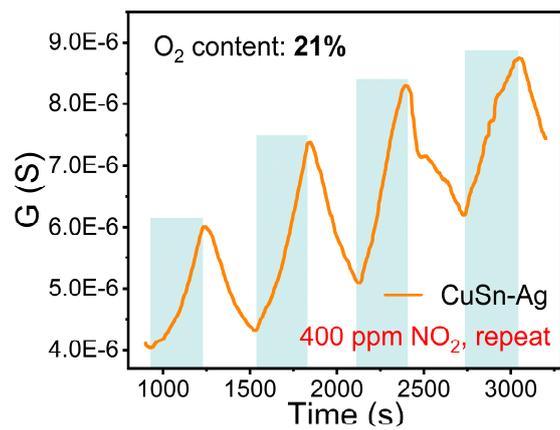


Fig. S7. Time-dependent conductance change of the sensor in response to 400 ppm NO_2 in the presence of 21% O_2 (air background) for repeated 4 experimental cycles.

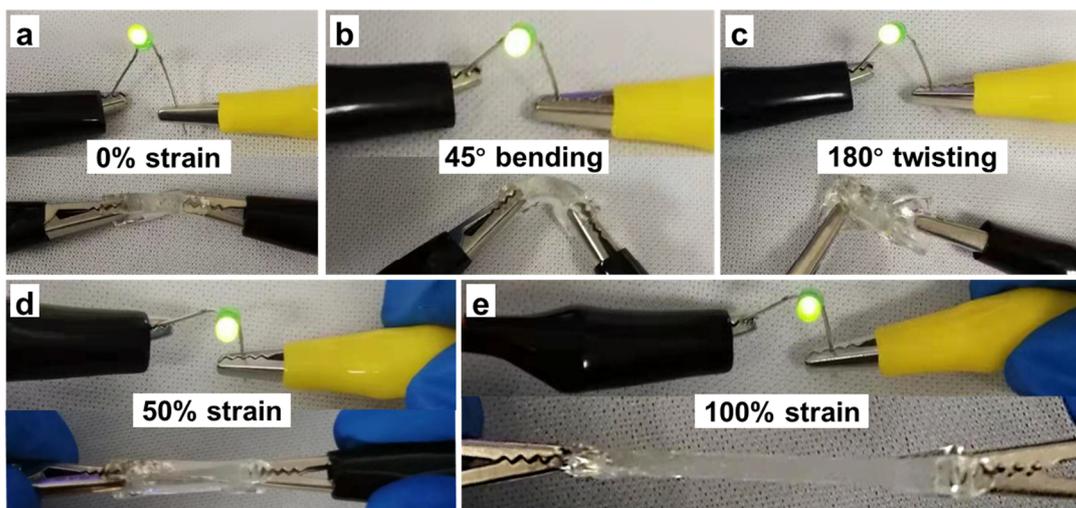


Fig. S8. The LED lights were lightened by a direct current power source when DN hydrogel was connected in series in the circuit. The LED light kept on when various deformations were applied to the hydrogel, including (a) 0% strain, (b) 45° bending, (c) 180° twisting, (d) 50% tensile strain, and (e) 100% tensile strain, indicating the maintained conductance.

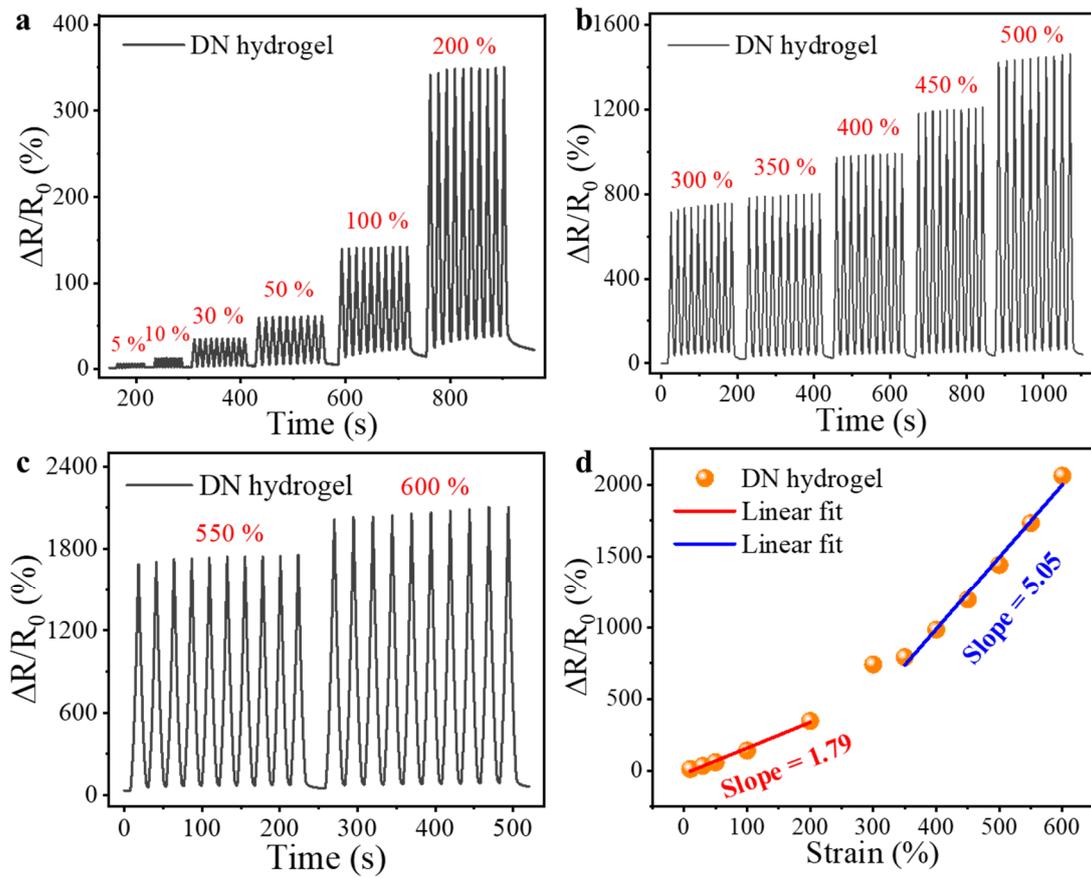


Fig. S9. Electromechanical response of the hydrogel sensor. (a-c) Dynamic curves showing the relative resistance changes of DN hydrogel upon loading and unloading a series of tensile strains from 5% to 600%. The strain sensing test was executed 10 times for each strain. (d) The linear fitted relative resistance changes versus strains, from which the gauge factors were deduced within different strain ranges.

Alarm demonstration system

The whole system consists of sensor, hardware system and software system. The hardware system is composed of voltage follower, signal conditioning circuit, power supply module, Bluetooth module, alarm module and Microprogrammed Control Unit (MCU), as shown in Fig. 7a-b. Among them, voltage follower circuit is used for stabilized output of Digital-to-Analog Converter (DAC), which ensures that the voltage at both ends of the sensor is constant. The signal output from the sensor was collected by the Analog to Digital Converter (ADC) of the MCU after passing through the signal conditioning circuit, and the data finally was sent to the user terminal via Bluetooth. Moreover, the alarm was triggered when the value collected by ADC was greater than the set value.

References

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